# Photon-induced zero-resistance states in electrons on He

D. Konstantinov\* and K. Kono



Low Temperature Physics Laboratory, RIKEN

# Talk outline

<u>Subject:</u> novel transport phenomena in nondegenerate 2D electrons subjected to perpendicular magnetic fields

- Quantum oscillations in degenerate 2DEG in semiconductors
- Radiation-induced ZRS in GaAs/AlGaAs
- Inter-subband resonance in electrons on He
- Quantum oscillations in electrons on He
- ZRS in electrons on He
- Conclusions and future plans

### Degenerate 2DEG in magnetic fields



Fermi statistics + Landau quantization



#### Radiation-induced ZRS in GaAs/AlGaAs



From Zudov et al. PRL 2003

 $\frac{hf}{\hbar\omega_c} = j \qquad - \text{ no change in resistance} \\ \frac{hf}{\hbar\omega_c} = j \pm \frac{1}{4} \qquad - \text{ resistance minima/maxima}$ 

Great number of theoretical proposals!



- 1. Negative-resistivity minima!
- 2.  $\sigma_{xx} < 0$  spontaneous symmetry breaking

Andreev et al. PRL 2003

# Non-degenerate 2D electrons on He



- Ultra-clean system with
   the highest mobility ~10<sup>8</sup> cm<sup>2</sup>/Vs
- Unscreened Coulomb interaction
- Low areal density  $< 2x10^8$  cm<sup>-2</sup>

At T=0 classical Wigner solid rather than degenerate gas!

In perpendicular *B*:  $E = \hbar \omega_c (l + \frac{1}{2}) \pm \frac{1}{2} g \mu_B B$ 

- Free-electron mass  $m^* \approx m_e$
- Free-electron g-factor: *g*=2.0023



#### Inter-subband resonance





Electric field  $E_{\perp}$ (V/cm)

Total energy in magnetic fields:

$$E = E_{\rm n} + \hbar\omega_{\rm c}(l + \frac{1}{2}), \quad l = 0, 1, 2, ...$$



# Electron dynamics in magnetic fields

Microwave excitation + scattering-mediated transitions. Scattering is quasi-elastic!



#### Magneto-resistance oscillations



Somewhat similar to Shubnikov de Haas effect

# Experiment

Au plated Corbino disk Magneto-transport measurements: gap 0.2 mm  $I = (\operatorname{Re}(G) + j \operatorname{Im}(G))V_0$ Determine complex admittance G  $G = G(\sigma_{xx})$ Find relationship between G and  $\sigma_{xx}$ 7777 More details on the poster! 100 GHz  $V_0$ 2 ••••••••• **1** B up to 0.85 T  $\vec{j} = \begin{pmatrix} \sigma_{xx} & \sigma_{yx} \\ \sigma_{yx} & \sigma_{yy} \end{pmatrix} E_x$ To tune in resonance!  $\rho_{xx} = \frac{\sigma_{xx}}{\sigma_{xx}^2 + \sigma_{xy}^2} \approx \frac{\sigma_{xx}}{\sigma_{xy}^2} \sim \sigma_{xx}$ 7777

### Oscillations



Without (w/o) radiation:

Drude low:  $\sigma_{xx} \approx \frac{\mu B^2}{e n_s}$ ,  $\mu B >> 1$ 

Many-electron effects

Dykman and Lea

New result:

Radiation-induced

resistivity oscillations!

#### Many-electron effects

$$\Delta(\sigma_{xx}^{-1}) = \sigma_{xx}^{-1}|_{with} - \sigma_{xx}^{-1}|_{w/o}$$

$$\int_{0}^{0} O = \int_{0}^{0} \frac{1.5x10^{7} \text{ cm}^{-2}}{4.4x10^{6} \text{ cm}^{-2}}$$

$$\int_{0}^{0} \frac{1.5x10^{7} \text{ cm}^{-2}}{4.4x10^{6} \text{ cm}^{-2}}$$

$$\int_{0}^{0} \frac{1.5x10^{6} \text{ cm}^{-2}}{4.4x10^{6} \text{ cm}^{-2}}$$



Tilting of Landau levels!

#### Periodicity



# Periodicity



#### Thermal broadening of LLs

Low density and sufficiently high fields  $\rightarrow$  ignore many-electron effects

Self-consistent Born approximation (SCBA):  $\Gamma \sim \hbar(\omega_c v)^{1/2}$ 

Decrease scattering by lowering T!



#### Thermal broadening of LLs



Fit with Gaussian lineshape:

Broadening due to vapor atoms

and ripplons in SCBA:

 $\Gamma^2 = \Gamma^2_{\rm atom} + \Gamma^2_{\rm rippl}$ 



#### **Conductivity decrease**

Upon increasing radiation power, there appears a negative contribution to  $\sigma_{xx}!$ 



### ZRS at T=0.2 K

The effect becomes stronger at lower T !



Vanishing conductivity  $\sigma_{xx}$  and resistivity  $\rho_{xx}$  at the minima!

#### Phase of oscillations



#### Oscillations in GaAs/AlGaAs

In GaAs/AlGaAs heterosctructures:

In our system:

$$\frac{B_{\rm f}}{B_{\pm}} = j \pm \frac{1}{4} , \quad j = 1, 2, \dots$$

$$\frac{B_{21}}{B_{\pm}} = l + \varphi_{\pm}(l) , \quad l = 4, 5, \dots$$



From Mani et.al. Nature 420, 646 (2002)

#### Oscillations in GaAs/AlGaAs

In GaAs/AlGaAs heterosctructures:

$$\begin{split} & \epsilon_{\underline{+}} = j + \alpha_{\underline{+}} j \ , \ \text{for} \ j \leq 4 \\ & \epsilon_{\underline{+}} = j + \frac{1}{4} \quad , \ \text{for} \ j > 4 \end{split}$$

In our system:

$$\frac{B_{21}}{B_{\pm}} = l + \varphi_{\pm}(l) , \quad l = 4, 5, \dots$$



From Zudov PRB, 69 (2004)

# Phase for minima

$$\frac{B_{21}}{B_{+}} = l + \varphi_{+}(l) , \quad l = 4, 5, \dots$$



$$Suppose \quad \phi_{+} = \alpha \ l \quad , \ \text{for} \ l \leq 4$$

Because

$$\frac{B_{21}}{B} = \frac{E_2 - E_1}{\hbar\omega_c}$$

Then at the minima:

$$E_2 - E_1 - l \hbar \omega_c = \frac{\alpha}{\alpha + 1} (E_2 - E_1)$$









Electron-electron interaction  $\rightarrow$  determines thermalization rate

Further decrease of density seems to eliminate the effect!



#### Instability and hysteresis



# Summary and plans

- Inter-subband magneto-oscillations in nondegenerate 2D electrons
- Allows to study dynamics of electrons in magnetic fields, e.g. collision broadening, many electron effects etc.
- Observed ZRS show striking similarities with zero-resistance effect in GaAs/AlGaAs heterostructures
- Study mechanism of zero-resistance effect in an ultra-clean system of classical electrons
- Extend to higher magnetic fields to cover regime  $hf = \hbar \omega_c$
- Microwave absorption in ZRS regime
- Quantum oscillations as a probe to resolve density of states